

Declaration For U.S. Patent Application

	Deciai au		.s. 1 atent Appi	ication .
As a below named is	nventor, I here	eby declare tha	at:	
I believe I am the or rst and joint invent for which a patent is	riginal, first an or (if plural n s sought on the	d sole invento ames are listed invention ent	d below) of the subject	listed below) or an original, f i matter which is claimed and lechnique on ozone wate
the specification of	which			
(Check one of 1, 2, or 3.)	2. × was Internated and was 3. was U.S. A	ational PCT A as amended or filed on	pplication No. PCT/JP/ (if applicable) rial No. (if applicable)	2003/010254 as
including the claim(s), as amended	d by any amen	dment referred to above	pove - identified specification,
application as define I hereby claim fore application for pater	ed in Title 37, ign priority but or inventor's	Code of Feder benefits under s certificate lis	ral Regulations, § 1.56. Title 35, United States sted below and have als	
(List prior	2002-235425	Japan	13/08/2002	Priority Claimed X Yes No
foreign applications.)	(Number)	(Country)	(Day/Month/Year Filed)	
	(Number)	(Country)	(Day/Month/Year Filed)	Yes No
		(C)	(D. (A. d. G) (D. D.)	Yes No
	(Number)	(Country)	(Day/Month/Year Filed)	
application listed be not disclosed in the Title 35, United Sta defined in Title 37,	benefit under low and, inso prior United tes Code, \$ Code of Fede	Title 35, Uni far as the sub States applicat 112, I acknow ral Regulation	ject matter of each of the tion in the manner prov ledge the duty to discl	o, of any United States patent ne claims of this application is yided by the first paragraph of lose material information as red bet ween the filing date of
	(Application Seri		ng Date) (Status)	
And I hereby appoi	nt as principa	il attorney and	d agent Ronald J. Kul	bovcik, Reg. No. 25,401; and

KUBOVCIK & KUBOVCIK	
Docket No	
Keiko T. Kubovcik, Reg. No. 40,428	3

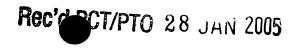
Please direct all communications to the following address:

Kubovcik & Kubovcik The Farragut Building Suite 710 900 17th Street, N.W. Washington, D.C. 20006 Phone: (202) 887-9023 Fax: (202) 887-9093

I hereby declare that all statements made here in of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

1-0	Full name of first or sole inventor: <u>Makoto Takemura</u>
• –	Inventor's Signature: Makoto Takemura Date: 05/01/2005
	Residence: <u>c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku</u>
	Tokyo 105-8634, Japan JPX
	Citizenship: Japan
	Post Office Address: Same as residence
2 (X)	Full name of second inventor: Yasuo Fukuda
2-00	Inventor's Signature: Yasur Fukuda Date: 05/01/2005
	Residence:c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634, Japan つアン
	Citizenship: Japan
	Post Office Address: Same as residence
	Full name of third inventor: Kazuaki Souda
	Inventor's Signature: kazuaki Souda Date: 05/01/2005
	Residence:c/o Sumitomo Mitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	Tokyo 105-8634, Japan
	Citizenship: Japan
	Post Office Address: Same as residence

Docket No	
Full name of fourth inventor: Masaaki Kato	
Inventor's Signature:	Date:
Residence: <u>c/o Puretron Ltd., 2023-15, Fujisaw</u>	ra-shi, Kanagawa 252-0816, Japan
Citizenship:Japan	
Post Office Address: Same as residence	
Full name of fifth inventor: <u>Eiji Suhara</u>	
Inventor's Signature:	Date:
Residence: c/o Echo Giken Co., Ltd., 1-13, Sh	inmachi 8-chome, Ome-shi, Tokyo 198-0024,
Japan	
Citizenship: Japan	
Post Office Address: Same as residence	



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As a below named	inventor, I herel	by declare that	nt:		
I believe I am the c t and joint inventor which a patent is	original, first and or (if plural nan sought on the in	I sole inventones are listed vention entitle	p are as stated below nex r (if only one name is li below) of the subject med (INSERT TITLE) 16	sted below) natter which echnique on	or an original, f irs is claimed and fo
the specification of	which				
(Check one of 1, 2, or 3.)	Interna and wa 3 was f U.S. A	iled on Augutional PCT As amended onpplication Se	ust 11, 2003 Application No. PCT/JP2 (if applicable) rial No	.003/010254 	
I hereby state that including the claim	I have reviewed (s), as amended	and understa	and the content of the abdment referred to above.	ove - identi	ified specification,
			ion which is material tral Regulations, § 1.56.	to the pa	tentability of this
application for pate	ent or inventor's ent or inventor's	certificate li	Title 35, United States sted below and have also aving a filing date befo	o identified	below any foreign
(List prior	2002-235425	Japan	13/08/2002	Priority Cla X Yes	
foreign applications.)			(Day/Month/Year Filed)		
				Yes _	No
	(Number)	(Country)	(Day/Month/Year Filed)		
				Yes _	No
	(Number)	(Country)	(Day/Month/Year Filed)		
	See att	ached list for	additional prior foreign app	olications	

I hereby claim the benefit under Title 35, United States Code, § 120, of any United States patent application listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56, which occurred bet ween the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.) (Filing Date) (Status)

And I hereby appoint as principal attorney and agent Ronald J. Kubovcik, Reg. No. 25,401; and Keiko T. Kubovcik, Reg. No. 40,428.



1

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Full name of first or sole inventor:	Makoto Takemura
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo M</u>	litsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634	, Japan
Citizenship: <u>Japan</u>	
Post Office Address: Same as re	sidence
	P.1. 1
	asuo Fukuda
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo M</u>	litsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634	, Japan
Citizenship: <u>Japan</u>	
Post Office Address: Same as re	sidence
	aki Hayata
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo M</u>	litsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634	, Japan
Citizenship: <u>Japan</u>	
Post Office Address: Same as re-	sidence
	·

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As a below named in	nventor, I hereb	y declare that:		
I believe I am the ori t and joint inventor r which a patent is so	iginal, first and (if plural namought on the inv	sole inventor (les are listed be vention entitled	elow) of the subject mat	ed below) or an original, f irs ter which is claimed and fo hnique on ozone water for
the specification of v	which			
(Check one of 1, 2, or 3.)	Internate and was find U.S. Ar	iled on <u>Augus</u> tional PCT Apps amended on	t 11, 2003 plication No. PCT/JP200 (if applicable) al No (if applicable)	03/010254 as
			d the content of the above ment referred to above.	ve - identified specification,
			n which is material to Regulations, § 1.56.	the patentability of this
application for paten	nt or inventor's nt or inventor's	certificate liste	ed below and have also	Code, § 119 of any foreign identified below any foreign that of the application for
(List prior foreign applications.)			13/08/2002 (Day/Month/Year Filed)	Priority Claimed X Yes No
				Yes No

___ See attached list for additional prior foreign applications

(Day/Month/Year Filed)

(Day/Month/Year Filed)

__ Yes ___ No

I hereby claim the benefit under Title 35, United States Code, § 120, of any United States patent application listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, § 1.56, which occurred bet ween the filing date of the prior application and the national or PCT international filing date of this application:

(Application Serial No.) (Filing Date) (Status)

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(Country)

(Number)

(Number)

And I hereby appoint as principal attorney and agent Ronald J. Kubovcik, Reg. No. 25,401; and Keiko T. Kubovcik, Reg. No. 40,428.



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Full name of first or sole inventor:	Makoto Takemura
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo M</u>	fitsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634	, Japan
Citizenship: <u>Japan</u>	
Post Office Address: Same as re	sidence
Full name of second inventor: V	asuo Fukuda
	Date:
_	
	litsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
	, Japan
Post Office Address: Same as re	sidence
	aki Hayata
Inventor's Signature:	Date:
Residence: <u>c/o Sumitomo M</u>	litsubishi Silicon Corporation, 2-1, Shibaura 1-chome, Minato-ku,
Tokyo 105-8634	, Japan
Citizenship: Japan	
Post Office Address: Same as re-	sidence

Inventor's Sig	nature:	Date:
Residence:	c/o Puretron Ltd., 2023-15, Fujisawa-shi,	Kanagawa 252-0816, Japan
Citizenship:	Japan	
Post Office A	ddress: Same as residence	
	nature: Eiji Suhara	
	rifth inventor: Eiji Suhara nature: Volume c/o Echo Gikon Co., Ltd., 1-13, Shinmac Japan	Date: Jan. 5. 201 chi 8-chome, Ome-shi, Tokyo 198-002